Intrinsic Channel Properties, Scattering Mechanisms, Quantum Transport Properties in Transition Metal Dichalcogenides

by

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DISSERTATION

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Advisor		

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This is a dedication.

"The fact that we live at the bottom of a deep gravity well, on the surface of a gas covered planet going around a nuclear fireball 90 million miles away and think this to be normal is obviously some indication of how skewed our perspective tends to be."

— Douglas Adams, The Salmon of Doubt: Hitchhiking the Galaxy One Last Time

ABSTRACT

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Abstract here

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List of Symbols

Symbol	Description	Unit
A	vector potential	$V \mathrm{s} \mathrm{m}^{-1}$
A	area	${\rm cm}^2$
A^{\star}	Richardson's constant	$\mathrm{As^{-1}K^2}$
B	magnetic field	T
C	capacitance	F
E	electric field	${ m Vm^{-1}}$
E	energy	eV (J)
$E_{ m F}$	Fermi energy	eV
E_g	bandgap energy	eV
$\hat{\mathbf{H}}$	Hamiltonian	eV (joule)
I	current	A
$I_{ m ds}$	drain current	A
L	length	μm
L	channel length	μm
m	mass	kg
m^{\star}	effective mass	kg
n	carrier density	${\rm cm}^{-2}$
n	charge carrier density	${ m Ccm^{-2}}$
$\hat{\mathbf{p}}$	momentum operator	$ m kgms^{-1}$
R	resistance	$k\Omega \mu m (\Omega)$
R_c	contact resistance	$k\Omega\mu m$
R_H	Hall coefficient	$\mathrm{m^3C^{-1}}$
$\hat{\mathbf{s}}$	spin operator	$\hbar \; (\mathrm{J} \mathrm{s})$

T	temperature	K
V	voltage	V
$V_{ m bg}$	backgate voltage	V
$V_{ m ds}$	drain voltage	V
$V_{ m H}$	Hall voltage	V
w	channel width	μm
μ	mobility	${\rm cm}^2{\rm V}^{-1}{\rm s}^{-1}$
$\mu_{ m B}$	magnetic moment	${ m eV}{ m T}^{-1}$
μ_e	electron mobility	${\rm cm}^2{\rm V}^{-1}{\rm s}^{-1}$
$\mu_{ ext{FE}}$	field-effect mobility	${\rm cm}^2{\rm V}^{-1}{\rm s}^{-1}$
$\mu_{ m H}$	Hall mobility	${\rm cm}^2{\rm V}^{-1}{\rm s}^{-1}$
μ_p	hole mobility	${\rm cm}^2{\rm V}^{-1}{\rm s}^{-1}$
ho	resistivity	$\Omega\mathrm{cm}$
$ ho_{xx}$	longitudinal resistivity	Ω
$ ho_{xy}$	transverse resistivity	Ω
σ	conductivity	μS
σ_{xx}	longitudinal conductivity	μS
σ_{xy}	transverse conductivity	μS
au	scattering time	S
$ au_{ m q}$	quantum scattering time	S
$\Phi_{ m B}$	barrier height	eV
$\Phi_{\mathrm{B}n}$	electron barrier height	eV
$\Phi_{\mathrm{B}p}$	hole barrier height	eV
Φ_M	metal work function	eV
Φ_S	semiconductor work function	eV
χ	electron affinity	eV
χ_S	semiconductor electron affinity	eV
ω_c	cyclotron frequency	Hz

List of Physical Constants

Symbol	Quantity	Value
$k_{ m B}$	Boltzmann's constant	$1.38066 \times 10^{-23}\mathrm{JK^{-1}}$
		$8.61734 \times 10^{-5}\mathrm{eV}\mathrm{K}^{-1}$
ϵ_0	dielectric constant	$8.85418 \times 10^{-12}\mathrm{A^2s^4kg^{-1}m^{-3}}$
e	elementary charge	$1.60218 \times 10^{-19}\mathrm{C}$
${ m eV}$	electron volt	$1.60218 \times 10^{-19}\mathrm{J}$
c	speed of light	$2.99792\times10^8\mathrm{ms^{-1}}$
h	Planck's constant	$6.62607 \times 10^{-34}\mathrm{Js}$
\hbar	reduced Planck's constant	$1.05457 \times 10^{-34}\mathrm{Js}\;(h/2\pi)$
$R_{\mathrm{K-90}}$	von Klitzing constant	25812.80745555Ω
m_e	electron mass	$9.109383 \times 10^{-31} \mathrm{kg}$
$k_{ m B}T$	Thermal energy	$0.02586\mathrm{eV}\ (T=27^{\circ}\mathrm{C})$
		$0.02526\mathrm{eV}\ (T=20^{\circ}\mathrm{C})$
μ_B	Bohr magneton	$9.274009\times 10^{-24}\mathrm{JT^{-1}}$
		$5.788381 \times 10^{-5}\mathrm{eV}\mathrm{T}^{-1}$
		$e\hbar/2m_e$ (atomic units)

Source: CODATA Recommende Values of the Fundamental Physics Constants: 2014, Mohr $et\ al.^1$

Conversion Factors

Conversion Factors	
1 Å	$=0.1\mathrm{nm}$
	$= 10^{-4} \mu \mathrm{m}$
	$=10^{-8} \mathrm{cm}$
	$= 10^{-10} \mathrm{m}$
$1\mu\mathrm{m}$	$=10\times10^4\mathrm{\AA}$
	$=10^3\mathrm{nm}$
	$= 10^{-4} \text{cm}$
	$= 10^{-6} \mathrm{m}$
1 eV	$= 1.60218 \times 10^{-19} \mathrm{J}$

	Powers of Ten	
10^{24}	yotta	Y
10^{21}	zetta	Z
10^{18}	exa	Е
10^{15}	peta	Р
10^{12}	tera	Τ
10^{9}	giga	G
10^{6}	mega	Μ
10^{3}	kilo	K
10^{2}	hecto	h
10^{1}	deka	da
10^{-1}	deci	d
10^{-2}	centi	\mathbf{c}
10^{-3}	milli	m
10^{-6}	micro	μ
10^{-9}	nano	n
10^{-12}	pico	p
10^{-15}	femto	f
10^{-18}	atto	a
10^{-21}	zepto	Z
10^{-24}	yocto	у

Acronyms

SB Schottky barrier

Chapter Title

1.1 Section Title

Contents here with Schottky barrier (SB).

Chapter Title

2.1 Section Title

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3.1 Section Title

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4.1 Section Title

References

[1] PJ Mohr, DB Newell, and BN Taylor. Codata recommended values of the fundamental constants 2014,(2015). arXiv preprint arXiv:1507.07956, 2015.